

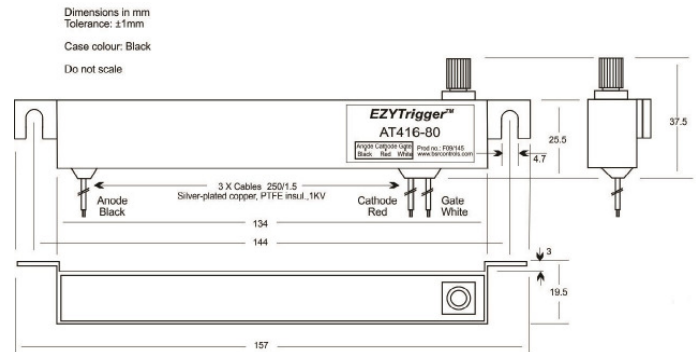
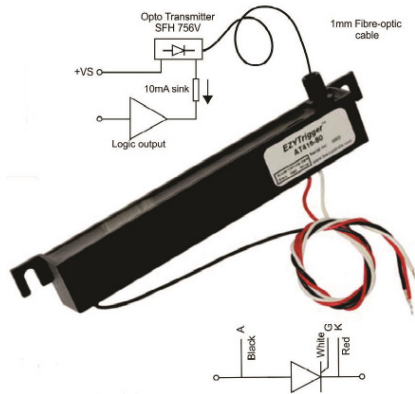
## AT 416

Line voltage 1250 and 2500V<sub>rms</sub>

### Applications:

- The trigger signal 10mA converts high-voltage thyristors into optically controlled devices
- Required gate current is derived from the anode of the thyristor via a controlled current source of 2.5A
- There is no need for an additional isolated power source for gate drive

- ⇒ The unit should be mounted in close proximity to the thyristor with leads as short as possible
- ⇒ If the unit is mounted directly on the heatsink, it is recommended that it be positioned on the heatsink with the same potential as the cathode of the thyristor.
- ⇒ This minimizes interference from fast-rising high-voltage spikes from the mains
- ⇒ For the same reason other leads should be kept away from the body of the trigger unit.
- ⇒ It is recommended that the minimum 5mA control current be increased to 10mA to allow for ageing of the optical components
- ⇒ If simultaneous triggering is required for a number of series-connected thyristors, it is advisable to use pulse shaping for the transmitter input.
- ⇒ An RC network with a time constant of 10µs can be used to create an initial current of 20mA, decaying to 10mA.
- ⇒ It is also advisable to maintain the control signal during the required conduction period of the thyristor.



### Absolute Maximum Ratings

### EZYTrigger Type

Parameter	Symbol	AT416 – 40	AT416 – 80
Peak voltage – positive and negative	V <sub>p</sub>	4000 V	8000 V
Nominal mains voltage	V <sub>m</sub>	1250 V	2500 V
Continuous DC voltage	V <sub>=</sub>	2500 V	2500 V
Thyristor turn-on time (t <sub>gate-delay</sub> + t <sub>r</sub> )	t <sub>on</sub>	6 µs	6 µs
Anode-Cathode transient immunity	(dv/dt) <sub>c</sub>	5000 V/µs	
Ambient temperature range	T <sub>a</sub>	-20°C to +85°C	

### Technical Data at 25°C

Parameter	Symbol	AT416 – 40	AT416 – 80
500 mA Gate current threshold	V <sub>gtl</sub>	40 V	40 V
2.5 A Gate current threshold	V <sub>gth</sub>	90 V	140 V
Gate current rise time ⇒ Anode voltage ⇒ 800V	(di/dt) <sub>g</sub>	1.2 A/µs	1.2 A/µs
Peak gate current	I <sub>p</sub>	2.5 A	2.5 A
Anode-cathode current at V <sub>p</sub> and I <sub>g</sub> = 0	I <sub>n</sub>	4 mA	4.6 mA
Maximum off-state gate current	I <sub>o</sub>	2 µA	2 µA
Minimum control current (SFH756 Transm./ 1m fibre)	I <sub>cm</sub>	5 mA	5 mA
Recommended control current (SFH756 Transm./ 1m fibre)	I <sub>c</sub>	10 mA	10 mA
Control input voltage drop at 10mA	V <sub>in</sub>	Typ 1.2 < 1.5V	Typ 1.2 < 1.5V
Maximum reverse control input voltage	V <sub>inr</sub>	6 V	6 V
Turn-on delay time at I <sub>control</sub> = 10mA	t <sub>di</sub>	7 µs	7 µs

All components and parts used in these units have been certified by their manufacturers as RoHS Compliant.

Epoxy filler is RoHS Compliant (2011/65/EU) and UL Approval meets UL94 V-0.

The Optocoupler is approved for UL1577 File No. E52744 System Code H or J, Double Protection and DIN EN 60747-5-2 (VDE0884), RoHS 2002/96/EC and WEEE (2002/96/EC).

No warranty is given for the accuracy of information stated by the respective manufacturers.